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We study the full counting statistics of electric current to several drain term inals with spindependent entrance conductances. We show that the statistics of charge transfers can be interpreted in terms of single electrons and spin-singlet pairs coming from the source. If the source contains transport channels of high transparency, a signi cant fraction of electrons comes in spin-singlet pairs.

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Spin-singlet pairs are of a fundam ental interest, since they provide a generic example of an entangled state [1, 2]. The entanglem ent presents a fundam ental difference between classical and quantum mechanics, and this has been unambiguously de ned and quanti ed in form of theorem s involving spin-singlets [3]. The modern developm ents in quantum information and manipulation have increased the interest in experimental demonstration of entanglem ent. W hile quantum optics presents signi cant experimental advances in this direction [4], the unam biguous experimental illustration of electron entanglem ent in solid state is still to be realized.

In recent years, a signi cant number of publications propose such experim ent in various solid-state nanostructures. In these proposals, most attention is paid to production and subsequent detection of spin-singlet pairs of electrons. A superconductor seem s to be a natural source of spin-singlet pairs, and di erent schem es involving a superconductor and norm al leads have been considered: two dots [5], two Luttinger liquids [6], two carbon nanotubes [7], or just two norm al leads [8]. It was suggested that exchange interaction can be used to produce singlets in a triple quantum dot device [9] and a 2D electron gas with four point contacts [10]. M ore recently, it was realized that norm al leads are a source of spin-entangled electrons [11]. The current noise was proposed to detect spin [12, 13, 14, 15] and orbital [16] entanglement. In Refs. [17] the full counting statistics (FCS) approach [18] was used to reveal the violation of a Clauser-Home inequality in multiterm inal devices. Charge current noise has been recently studied in system s com bining ferrom agnets and norm alm etals [19]. FCS of spin currents in a two-term inaldevice has been addressed in [20].

In this Letter, we consider an almost traditional method of spin detection that relies on spin sensitivity of the conductance of a norm alm etal-ferror agnet interface [21]. We demonstrate that one does not have to do anything special to produce spin-singlets: they are readily present in almost any ow of degenerate electrons, and the FCS of currents in spin-sensitive drains reveals this circum stance. We do not consider any other type of entanglement than that of a spin-singlet pair. We

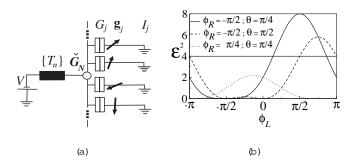


FIG.1: (a) The setup considered. The coherent conductor (black rectangular) is a source of electrons being transferred to the drains: spin-sensitive tunnel junctions. The probabilities of one- and two-electron transfers are extracted from m easurement of the currents I_j in the drains and their correlators. (b) The square of B ell's parameter for the setup described in the text plotted versus the switching angle L arccosn L $\frac{6}{3}$ for several values of R arccosn R $\frac{6}{3}$ and $\arccos n_L$ $\frac{6}{3}$ when all vectors are coplanar. The values of E^2 above the horizontal line violate B ell's inequality.

consider a generic coherent conductor characterized by a set of transm ission eigenvalues T_n . The conductor is assumed to be short enough for no spin-scattering taking place while an electron traverses the conductor, so that each transport channel n is spin-degenerate. The fraction of electrons coming in spin-singlet pairs is eventually $_n T_n^{2} = _n T_n$, 2=3 for a di usive conductor.

To see that a signi cant part of electrons comes in spin-singlets, we concentrate on a multi-term inal setup (Fig. 1 (a)), which consists of a coherent conductor representing the source of electrons and several drains, the conductances of which depends on spin. The sim plest way to achieve this is to connect ferrom agnetic leads to a norm alm etallic island [21, 22]. Spin-sensitive conductance can also be realized with sem iconductor quantum dots in a magnetic eld [23]. In our proposal, the drains are to detect the electron propagation via the coherent conductor. They thus should not disturb much the electron ow. This is ensured by the total conductance G_d of the drains being much bigger than the conductance

of the \source". This is easy to realize if there are m any transport channels opening to the drains, i.e. $G_d = e^2 = \sim$, which we assume. The electron spin should not change when the electrons propagate from the \source" to the drains, which im plies that the size of the norm al island should not exceed the spin relaxation length. We will study zero-frequency (cross) cum ulants of electric current in the drains: the FCS of electron transfers.

The advantage of the FCS approach to quantum transport is that it not only gives num erical values of various cumulants of the charge transferred, but also allows to identify elementary independent events of transfer. Elementary events are de ned as follows: the generating function (de ned in Eq. (1) below) can be presented as S / $_{\rm n}$ ln Z $_{\rm el}$ (n), Z $_{\rm el}$ (n) being a polynom ial in X i = expi i. This implies that the FCS can be interpreted as com position of elem entary events characterized by the generating function $Z_{el}(n)$. If the coe cients of ^m ^j X X 1 ^m 1 are real and positive, they can be inte preted as probabilities that m $_{\rm j}$ electrons were transm itted through channeln to term inal j in the course of the elem entary event. This facilitates the interpretation and understanding of quantum transport. The FCS indeed reveals the many-body aspect of transport. In principle one may have elementary events involving many particles. Ref. [18] shows that for two-term inal nonferrom agnetic devices elem entary events involve only one electron.

It is convenient to work with the generating function of FCS de ned in such a way that the probability P (N) to transfer N electrons during a time interval reads

$$P(N) = \frac{d}{2} \exp(S() \text{ in })$$
: (1)

For a coherent conductor biased at voltage eV $$k_{\rm B}\,{\rm T}$$, the cum ulant generating function (CGF) is given by [18]

S() =
$$\frac{eV}{r} X$$
 ln (R_n + T_n exp(i)); (R_n 1 T_n):

Interpretation of this in terms of elementary events is as follows: In each transport channel n, electrons make eV = ~ independent attempts to traverse the conductor. A n attempt is successful with probability T_n . Let us generalize this to our setup assuming at the moment that the conductances of the drains are not spin-sensitive. To account for electron transfers to each drain j, we introduce multiple counting elds j. The CGF reads

S (f jg) =
$$\frac{eV}{\sim} \frac{X}{n} \ln (R_n + T_n) \frac{X}{j} p_j^{(0)} e^{i_j A}$$
 : (2)

This also allows for evident interpretation: after a successful attempt to traverse the conductor, the electron gets to the drain j with probability $p_j^{(0)}$. These probabilities are nothing but the norm alized conductances of the drains, $p_j^{(0)} = G_j = \begin{bmatrix} P \\ k \end{bmatrix} G_k$, so that $\begin{bmatrix} P \\ j \end{bmatrix} p_j^{(0)} = 1$.

Now we are ready to formulate the main quantitative result of our work. If the conductances of the drains are spin-sensitive, the CGF reads

$$S = \frac{eV}{2 \sim} \prod_{n}^{X} \ln 4R_{n}^{2} + 2R_{n}T_{n} \prod_{j}^{X} p_{j}e^{i_{j}}$$

$$+ T_{n}^{2} \prod_{j\neq k}^{X} p_{j,k}e^{i(j+k)5} : (3)$$

The interpretation in terms of elementary events is as follows: The electrons in each transport channel make eV =2 ~ independent attempts to traverse the conductor. The outcom es of each attem pt are: a) with probability R_n^2 , no electron is transferred, b) with probability $2R_n T_n$, one electron traverses the conductor, c) with probability T_n^2 , two electronsm ake it. At the next stage, rif one electron is transferred, it goes to the drain j with probability pi. If two electrons are transferred, the probability to have one electron transferred to the drain j and another to the drain k equals $2p_{ik}$ jkpj;j. If the drains are not sensitive to spin, $p_{j;k} = p_j p_k$, and we recover Eq. (2). If they are, $p_{j,k} \in p_j p_k$ in general. The concrete form of pik allows us to prove that if two electrons are transferred, they are transferred in spin-singlet state. We notice that elementary processes form ing low frequency FCS in multiterm inal setups can, in principle, involve many particles [18]. The fact that in our specic setup an elementary event involves no more than two particles is a result of calculation and was not assum ed apriori. A lso, no expansion in the transm ission values T_n was adopted to $\lim it$ the elementary processes to two-electron ones, but the form ulas are exact analytical expressions for the setup considered. We show that the two-electron process is a transfer of a spin-singlet pair, and this is the main result of our paper.

Let us give the concrete form for $p_{j,k}$. The spindependent conductance of each drain can be presented as $G_j(1 + g_j^{)})$, ^ being a vector of Paulim atrices, and g_j being parallel to the magnetization direction of the corresponding ferrom agnet. The conductances for majority (m inority) spins are thus $G_j(1 + j_{j,j})$ ($G_j(1 - j_{j,j})$). Since conductances m ust rem ain positive, $j_{j,j}j = 1$. The probabilities under consideration read

$$p_j = p_j^{(0)} \frac{1 - \overline{g}_j g}{1 - \overline{g}_j^2};$$
 (4a)

$$p_{j;k} = p_{j}^{(0)} p_{k}^{(0)} \frac{1}{1} \frac{g_{j}}{g_{j}} \frac{g_{j} + (\overline{g} - g_{j})}{1 - \overline{g}^{2}}; \quad (4b)$$

where we introduced a weighted quantity $\overline{g} = \int_{j}^{F} p_{j}^{(0)} g_{j}$. Eqs. (3,4) determ ine the FCS in our setup and thus present the quantitative results of our work.

Before discussing the probabilities (4), their manifestation in the (cross) cum ulants of the currents, and their relation to spin-singlets, let us outline the derivation of Eqs. (3), and (4). Our starting points are the G reen function theory for FCS and its circuit-theory extension to the multi-term inalcase [24]. We extend this technique to spin-dependent conductances in the spirit of Ref. [22]. In this technique, one works with K eldysh G reen functions that are 4 4 m atrices in K eldysh and spin index.

The G reen functions G_s in the source lead and G_j in the drain leads are xed and determ ined by lling factor f_s ("); f_j (") and counting eld $_j$ in the corresponding lead. They are scalars in spin space and read

G() =
$$e^{i_z} = 2$$
 1 2f 2f $e^{i_z} = 2$;
2(1 f) 2f 1 $e^{i_z} = 2$;

 $_{\rm z}$ being the diagonal Paulim atrix in K eldysh space. The G reen function G $_{\rm N}\,$ in the node is determined from the balance of (spin-dependent) matrix currents via all the connectors [24]. For the source, the matrix current is [25]

$$I_{s}(f g) = \frac{e^{2}}{2} \sum_{n}^{X} \frac{T_{n} G_{s};G_{N}}{1 + T_{n} G_{s};G_{N} 2 = 4};$$
 (5)

where [:::] (f:::g) denote (anti)commutator of two matrices. As to the matrix currents through spin-sensitive drains, they acquire spin structure. We assume that the norm alm etal-ferrom agnet interfaces are tunnel junctions so that all transmission eigenvalues 1: it is known that tunnel junctions provide the best spin sensitivity [21]. The current can be derived with Tunneling Ham iltonian m ethod and reads

$$I_{j} = \frac{G_{j}}{2} (1 + g_{j}) G_{j}; G_{N} :$$
 (6)

This relation has been rst derived in Ref. [26] in the superconducting context and is valid here owing to universality of matrix structure of G . Provided G $_{\rm N}$ is found, the CGE can be determined from the relation $0S=0_{j}=$ $(=8e^2)$ d"Trf _zI_jg. To determ ine G_N, one generally has to solve the current balance equation $I_s + j I_j = 0$, with the constraints $G_N^2 = 1$ and $TrG_N = 0$. However, in the general case, the solution is complicated by multiple electron trips from the drains to the source and back. W e do not wish to account for this, since in our setup the drains are m erely detectors and are not supposed to perturb the electron ow. So we will solve this equation only in the corresponding limiting case G_d G_s. This means that $G_{\,N}\,$ is to be determ ined from the balance of the drain currents only, $_{j}I_{j} = 0$. The source matrix current is found by substitution of the solution into Eq. (5). We consider only the shot noise lim it eV $k_B T$. In this case, the contribution to FCS comes from the energy strip of width eV where $f_s = 1$; $f_1 = 0$. From current conservation, one proves that in this lim it

$$S = \frac{eV}{2} X Trln 1 + \frac{T_n}{4} fG_s; G_N g 2 :$$

W e have that the solution $G_{\,N}\,$ reads

$$G_{N} = \frac{1}{0+2} + \frac{0}{1};$$

with $_{0} = 2 (p \ \overline{g} \ g = (1 \ \overline{g}^{2})_{p} = 2 (g \ p \ \overline{g} + \overline{g} \ p \ \overline{g}, g)) = (1 \ \overline{g}^{2}), p \ _{j} (G_{j} = G_{d}) e^{i_{j}},$ and $g \ _{j} (G_{j} = G_{d}) e^{i_{j}} g_{j}$. Substituting the concrete expressions for the G reen functions, we arrive at Eq. (3), with probabilities given by (4).

Now we are in the position to discuss and interpret the probabilities (4). Let us rst consider the case $\overline{g} = 0$. A lthough it is not the most general case, the conductances of the drains can be tuned to achieve this. The expressions for probabilities are simpler in this case:

$$p_j = p_j^{(0)}; p_{j,k} = p_j^{(0)} p_k^{(0)} (1 \quad g_j \quad g):$$
 (7)

Thus, the one-electron probability to get into a certain drain does not depend on all other drains, except that it is determined by the normalized conductance of the drain. It is not sensitive to electron spin either. In contrast to this, the two-electron probability does depend on spin. The concrete expression for two-electron probability can be re-derived if one starts with the two-particle density matrix of the spin-singlet state

$$\gamma_{\rm sing} = \frac{1}{4} \ \hat{1} \ \gamma_1 \ \gamma_2 \ ; \tag{8}$$

1;2 num bering the particles. For one particle, the probability to tunnel to a certain drain is proportional to $TrfG_{j}(1 + g_{j})^{g}$. Consequently, the probability for two particles to tunnel to the drains j and k is proportional to $TrfG_{j}G_{k}(1 + g_{j})^{1}(1 + g_{k})^{2} + (1)$. U sing the spin-singlet density m atrix, we recover Eq. (7). This not only m eans that the electrons com e w ith opposite spin, but also the probabilities distinguish between spin-singlet and a component of the triplet state w ith opposite spin.

Let us put these probabilities in the context of general discussion of the relations between locality and quantum entanglem ent that provide the initial fascination with the subject [1]. Let us assign classical observers, A lice and B obto two of the drains. Let us also disregard the current uctuations of the source and just let it pass a xed num ber of electrons. The observers can change the direction of $g_{\mathbb{A}}\,_{;\mathbb{B}}\,$ in their own drains. If only one-electron processes occur, the readings of A lice and B ob would be uncorrelated. One can interpret this as locality: the counted electrons are independent, and an electron counted by A lice would never get to B ob passing inform ation about direction of g_A . How ever, if spin-singlets are com ing, the readings do correlate by virtue of Eq. (7). If B ob knows the readings of A lice, he can compare it with his own observations and gure out the direction of her g_A [27].

In the general case, $\overline{g} \in 0$, the probabilities are less straightforward to interpret. The one-electron probability for a given drain does depend on the g_1 of the other

drains by m eans of \overline{g} . The reason for this is transparent: there is spin accumulation in the node [21, 22]. The \overline{g} is the average polarization of electrons in the node. In fact, the one-electron probabilities can be re-derived assuming that one-particle density matrix reads $^{=}(\widehat{1} - \overline{g}^{-})=2$. The two-particle density matrix reads

$$^{\circ} = \frac{1}{4} \hat{1} (1 - g^{\circ})^{\circ}_{1} \hat{2} (\overline{g}^{\circ}_{1}) (\overline{g}^{\circ}_{2}) ; \qquad (9)$$

This density matrix is the mixture of the singlet density matrix and of the $(^{1} + ^{2}) - g = 0$ component of the triplet density matrix, with respective weights $1 - \overline{g}^{2} = 2$ and $\overline{g}^{2} = 2$. We stress that Eq. (9) gives the density matrix of electrons that go to drains, and not the one of electrons coming from the source: They still come in spin-singlet pairs. Spin accumulation thus distorts this matrix, both for single electrons and electron pairs.

The elementary probabilities $p_j; p_{j,k}$ can be readily extracted from the measurement of average currents I_j and low-frequency noise (correlations) S_{jk} in the drains, since

$$I_{j} = Ip_{j}; \qquad (10a)$$

$$S_{jk} = 2eI[(p_{j,k} 2p_jp_k) + p_{j,k}];$$
 (10b)

I being the current in the source, and $P_n T_n^2 = P_n T_n$ giving the fraction of electrons coming in spin-singlet pairs. is related to the Fano factor F (ratio of noise to 2eI) of the source, = 1 F. We notice that, in contrast to optics, the measurement is not time resolved, since we access FCS at low frequency, at times much longer than time intervals between electron transfers.

The simplest illustration is a ballistic quantum point contact ($T_n = 1$) as source and two drains 1, 2 that can only accept electrons with spin up (1) and down (2). This implies that all electrons come in spin-singlet pairs and, since $g_1^z = -\vec{q} = 1$, $p_1 = p_2 = 1=2$, $p_{11} = p_{22} = 0$, $p_{12} = 1=2$. Therefore the same amount of electrons go to the drains 1 and 2, and there is an absolute correlation of the currents in the drains, $S_{11} = S_{22} = S_{12} = 0$!

We demonstrate that our setup can be used to illustrate the violation of a Bell-C lauser-H ome-Shim ony-H olt inequality [3]. We consider four drains. The drains 1;2 and 3;4 are pairwise antiparallel, i.e. $g_1 = g_2 = g_L$, $g_3 = g_4 = g_R$. For simplicity, $G_1 = G_2$ and $G_3 = G_4$.

This is a close analogue of the optical experiments [4]. Each pair of drains form s a \spin detector": e.g. the current through drain 1 (2) measures the number of electrons coming with spin up (down) with respect to g_L . The $j_{L,R}$ jtum out to be the detectors' e ciencies. The measurements are performed with each polarization taking two directions, $n_{L,R}$; $n_{L,R}^0$ ($n_{L,R}^2 = n_{L,R}^{0^2} = 1$). We shall discard the events where both electrons of a singlet go to the same detectors. For instance, the probabilities to go to di erent detectors. For instance, the probability to measure spin up in the left and right detectors reads $P_{++} = p_{1;3} = (p_{1;3} + p_{1;4} + p_{2;3} + p_{2;4})$.

The Bell parameter is de ned as E $f(n_L;n_R) + E(n_L^0;n_R) + E(n_L;n_R^0) = P_{++} + P = P_{+}$ lator is given by $E(n;n^0) = P_{++} + P = P_{+}$ P_{+} . From Eq. (7) we obtain that $E = q_{L-1}g$. The Bell parameter is proportional to e ciencies of both detectors, $E = g_{L-1}g_R + p_{L-1} + n_{L-1} + n_{L-1}$

To conclude, we have shown that the low-frequency FCS of a coherent conductor can be interpreted in terms of single-electron and spin-singlet pairs transfers. This can be revealed and quanti ed by using spin-sensitive drains.

larization exceeds 2 $^{1=4}$ ' 84% , in agreem ent with [15].

WeplotE in Fig.1(b).

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